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Vishay Semiconductor/Diodes Division VS-10MQ040-M3/5AT

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-10MQ040-M3/5AT - DIODE SCHOTTKY 40V 1.5A DO214AC

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VS-10MQ040-M3

Vishay Semiconductors

Schottky Rectifier, 1 A



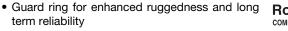
Cathode Anode

DO-214AC (SMA)

PRODUCT SUMMARY		
Package	DO-214AC (SMA)	
I _{F(AV)}	1 A	
V _R	40 V	
V _F at I _F	0.49 V	
I _{RM}	26 mA at 125 °C	
T _J max.	150 °C	
Diode variation	Single die	
E _{AS}	3.0 mJ	

FEATURES

• Low forward voltage drop



RoHS COMPLIANT HALOGEN

FREE

- Halogen-free according to IEC 61249-2-21 definition
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\mathrm{C}$
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-10MQ040-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	DC	1	A		
V _{RRM}		40	V		
I _{FSM}	t _p = 5 μs sine	120	А		
V _F	1.5 A _{pk} , T _J = 125 °C	0.56	V		
TJ	Range	- 55 to 150	C°		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10MQ040-M3	UNITS		
Maximum DC reverse voltage	V _R	40	V		
Maximum working peak reverse voltage	V _{RWM}	40	v		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current		50 % duty cycle at T_L = 123 °C, On PC board 9 mm ² island (0.013 mm thick copper pad area	C C	1.5	٨
See fig. 4	IF(AV)	50 % duty cycle at $T_L = 132$ °C, On PC board 9 mm ² island (0.013 mm thick copper pad area	C C	1	A
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А
See fig. 6	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	30	~
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s1.0Frequency limited by T _J maximum V _A = 1.5 x V _R typical1.0		А	

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VS-10MQ040-M3

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T _{.1} = 25 °C	0.54	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1.5 A	1j=25 0	0.62	
See fig. 1	V FM ("	1 A	T. 105 °C	0.49	
		1.5 A	T _J = 125 °C	0.56	
Maximum reverse leakage current	L	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA
See fig. 2	I_{RM} $T_J = 125 \text{ °C}$ $V_R = Rated V_R$	V _R = nateu V _R	26	IIIA	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.36	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}, T_J = 25 \text{ °C}, \text{ test signal} = 1 \text{ MHz}$ 38		pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0 n		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/μs		V/µs	

Note

 $^{(1)}\,$ Pulse width = 300 $\mu s,$ duty cycle = 2 $\,\%$

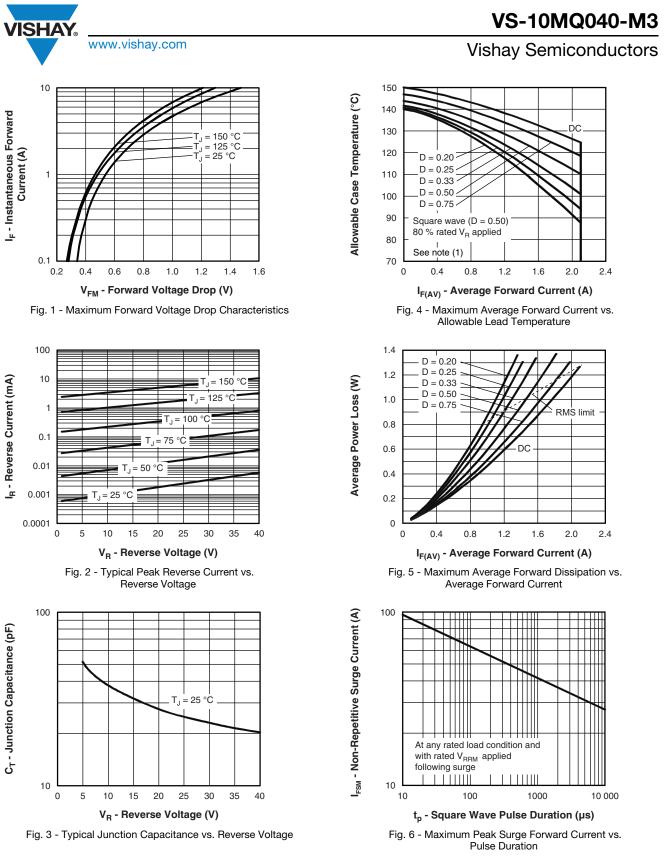
THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W
Approvimate weight			0.07	g
Approximate weight			0.002	oz.
Marking device		Case style SMA (similar D-64)	1	F

Note

⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

2





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

Revision: 11-Oct-11

3

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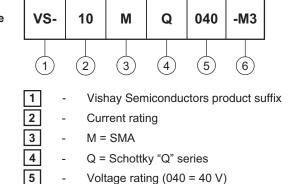
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VS-10MQ040-M3

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ORDERING INFORMATION TABLE

Device code



- Environmental digit:

6

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	FERRED P/N PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGE				
VS-10MQ040-M3/5AT	5AT	7500	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95400			
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		

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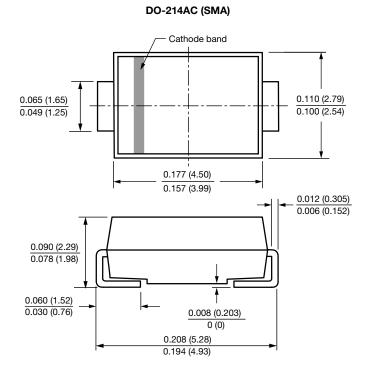


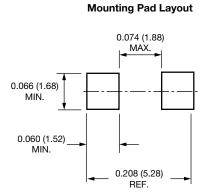
Outline Dimensions

Vishay Semiconductors

SMA

DIMENSIONS in inches (millimeters)









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